Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.502 inches

Mounting Facility Quantity:

1

### Mounting Method:

Threaded stud

#### **Overall Width Across Flats:**

0.557 inches

**Thread Size:** 

0.250 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

25.0 breakover voltage, dc

Current Rating Per Characteristic:

80.00 amperes forward current, average absolute

### Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector blank

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnpn

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

Fiig:

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